

SUB75P03-07, SUP75P03-07

Vishay Siliconix

P-Channel 30 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A) ^a	
- 30	0.007 at V _{GS} = - 10 V	± 75	
- 30	0.010 at V _{GS} = - 4.5 V	± 75	

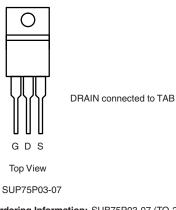
TO-263

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SUB75P03-07

Н G D S Top View

TO-220AB

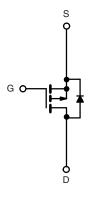


Ordering Information: SUB75P03-07 (TO-263) SUB75P03-07-E3 (TO-263, Lead (Pb)-free) SUP75P03-07 (TO-220AB) SUP75P03-07-E3 (TO-220AB, Lead (Pb)-free)

FEATURES

Compliant to RoHS Directive 2002/95/EC





P-Channel MOSFET

ABSOLUTE MAXIMUM RAT	INGS (T _C = 25 °C, unless other	wise noted)			
Parameter	Symbol	Limit	Unit		
Gate-Source Voltage		V _{GS}	± 20	V	
Continuous Drain Ourrent (T. 175 %)	T _C = 25 °C		- 75 ^a	٨	
Continuous Drain Current (T _J = 175 °C)	T _C = 125 °C	ID	- 65		
Pulsed Drain Current		I _{DM}	- 240	A	
Avalanche Current		I _{AR}	- 60		
Repetitive Avalanche Energy ^b	L = 0.1 mH	E _{AR}	180	mJ	
Power Dissipation	$T_{\rm C}$ = 25 °C (TO-220AB and TO-263)	Р	187 ^d	W	
Fower Dissipation	T _A = 25 °C (TO-263) ^c	P _D	3.75		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS				
Parameter		Symbol	Limit	Unit
Junction-to-Ambient	PCB Mount (TO-263) ^c	D	40	°C/W
	Free Air (TO-220AB)	– R _{thJA}	62.5	
Junction-to-Case		R _{thJC}	0.8	

Notes:

a. Package limited.

b. Duty cycle \leq 1 %.

c. When mounted on 1" square PCB (FR-4 material).

d. See SOA curve for voltage derating.

* Pb containing terminations are not RoHS compliant, exemptions may apply.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = -250 \mu A$	- 30			V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	- 1		- 3	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
		$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$			- 1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = - 30 V, V_{GS} = 0 V, T_{J} = 125 °C			- 50		
		$V_{DS} = -30 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 175 ^{\circ}\text{C}$			- 250		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} = -5 V, V_{GS} = -10 V$	- 120			А	
		V _{GS} = - 10 V, I _D = - 30 A		0.0055	0.007	Ω	
	Б	V_{GS} = - 10 V, I _D = - 30 A, T _J = 125 °C			0.010		
Drain-Source On-State Resistance ^a	R _{DS(on)}	V_{GS} = - 10 V, I _D = - 30 A, T _J = 175 °C			0.013		
		$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -20 \text{ A}$		0.008	0.010		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 75 A	20			S	
Dynamic ^b		· · · · · ·					
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = - 25 V, f = 1 MHz		9000		pF	
Output Capacitance	C _{oss}			1565			
Reversen Transfer Capacitance	C _{rss}			715			
Total Gate Charge ^c	Qg			160	240	nC	
Gate-Source Charge ^c	Q _{gs}	V_{DS} = - 15 V, V_{GS} = - 10 V, I_{D} = - 75 A		32			
Gate-Drain Charge ^c	Q _{gd}			30			
Turn-On Delay Time ^c	t _{d(on)}			25	40	- ns	
Rise Time ^c	t _r	V_{DD} = - 15 V, R _L = 0.2 Ω I _D \cong - 75 A, V _{GEN} = - 10 V, R _g = 2.5 Ω		225	360		
Turn-Off Delay Time ^c	t _{d(off)}			150	240		
Fall Time ^c	t _f			210	340		
Source-Drain Diode Ratings and Cha	racteristics ^b	(T _C = 25 °C)					
Continuous Current	۱ _S				- 75	•	
Pulsed Current	I _{SM}				- 240	A	
Forward Voltage ^a	V _{SD}	I _F = - 75 A, V _{GS} = 0 V		- 1.2	- 1.5	V	
Reverse Recovery Time	t _{rr}			55	100	ns	
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = - 75 A, dl/dt = 100 A/μs		2.5	5	Α	
Reverse Recovery Charge	Q _{rr}	1		0.07	0.25	μC	

Notes:

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

c. Independent of operating temperature.

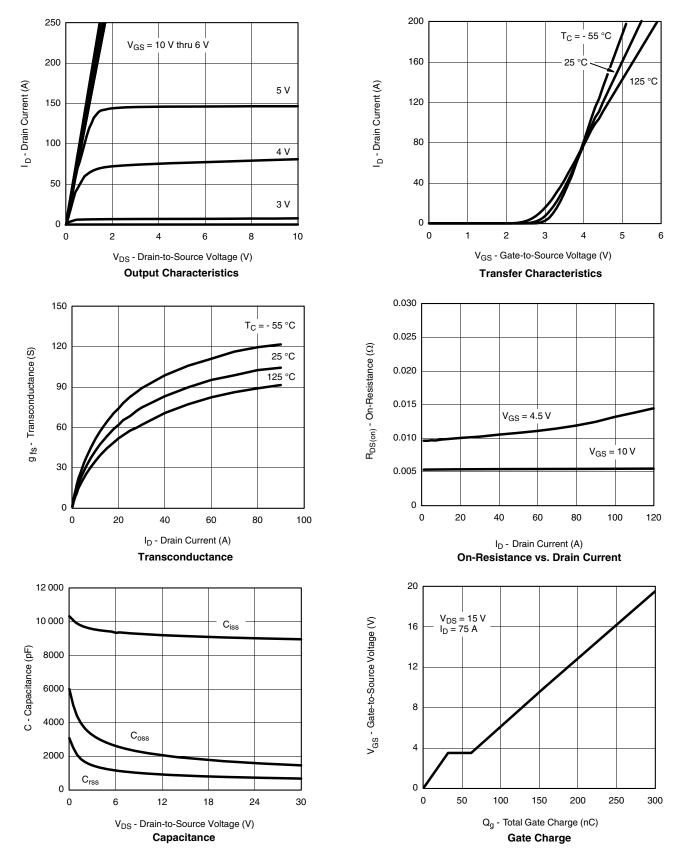
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

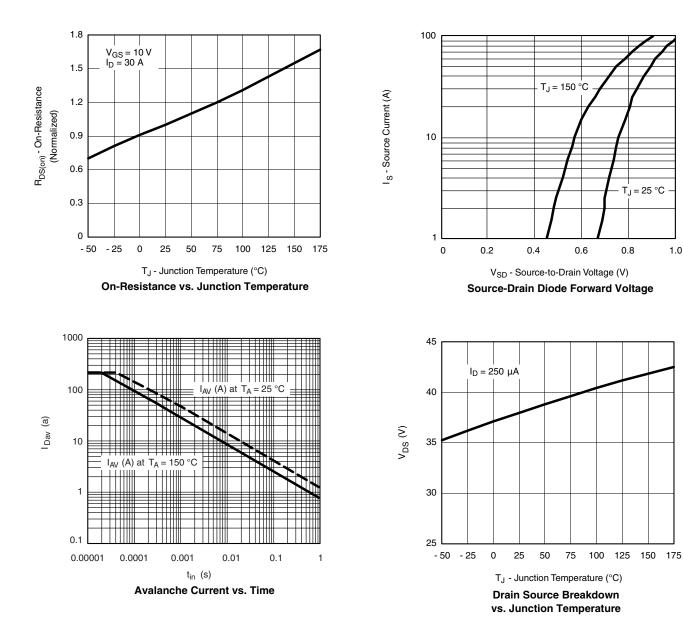


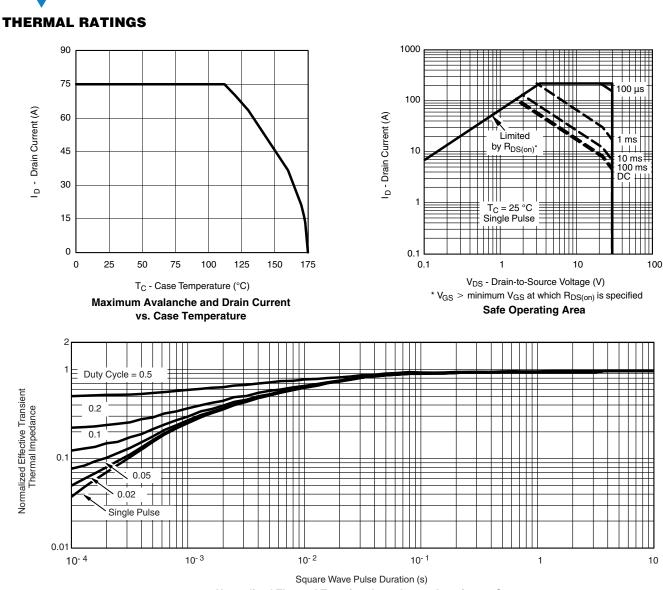
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





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Normalized Thermal Transient Impedance, Junction-to-Case

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